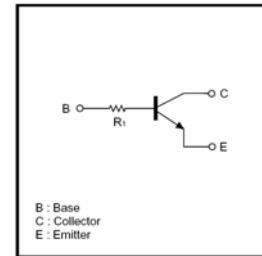


Features

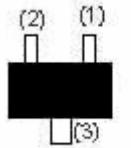
1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
3. Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



PIN CONNECTIONS AND MARKING

DTC143TE

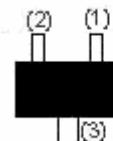


(1) Base
(2) Emitter
(3) Collector

SOT-523

Addreviated symbol: 03

DTC143TUA

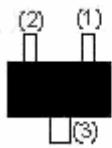


(1) Base
(2) Emitter
(3) Collector

SOT-323

Addreviated symbol: 03

DTC143TKA

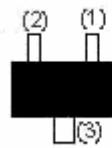


(1) Base
(2) Emitter
(3) Collector

SOT-23-3L

Addreviated symbol: 03

DTC143TCA

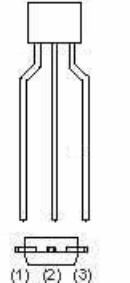


(1) Base
(2) Emitter
(3) Collector

SOT-23

Addreviated symbol: 03

DTC143TSA



(1) Emitter
(2) Collector
(3) Base

TO-92S

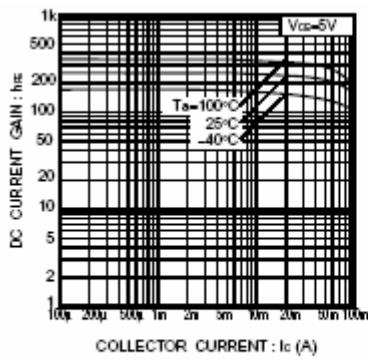
Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTC143T□)					Unit
		E	UA	CA	KA	SA	
Collector-base voltage	$V_{(BR)CBO}$			50			V
Collector-emitter voltage	$V_{(BR)CEO}$			50			V
Emitter-base voltage	$V_{(BR)EBO}$			5			V
Collector current	I_C			100			mA
Collector Power dissipation	P_C	150		200		300	mW
Junction temperature	T_j			150			°C
Storage temperature	T_{stg}			-55~150			°C

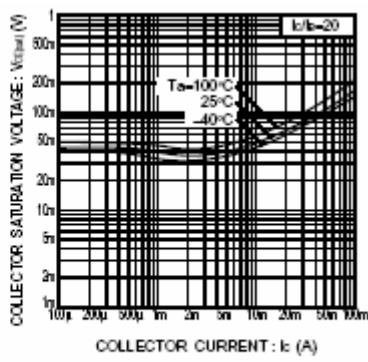
Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Collector-base breakdown voltage	$V_{(BR)CBO}$	50			V	$I_C=50\mu A$
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	50			V	$I_C=1mA$
Emitter-base breakdown voltage	$V_{(BR)EBO}$	5			V	$I_E=50\mu A$
Collector cut-off current	I_{CBO}			0.5	μA	$V_{CB}=50V$
Emitter cut-off current	I_{EBO}			0.5	μA	$V_{EB}=4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$			0.3	V	$I_C=5mA, I_B=0.25mA$
DC current transfer ratio	h_{FE}	100		600		$V_{CE}=5V, I_C=1mA$
Input resistance	R_I	3.29	4.7	6.11	KΩ	
Transition frequency	f_T		250		MHz	$V_O=10V, I_O=5mA, f=100MHz$

Typical Characteristics



COLLECTOR CURRENT : I_C (A)
Fig.1 DC current gain vs.
collector current



COLLECTOR CURRENT : I_C (A)
Fig.2 Collector-emitter saturation
voltage vs. collector current